

RF AMPLIFIER

MODEL *TM3035*

Available as: TM3035, 4 Pin TO-8 (T4)
 TN3035, 4 Pin Surface Mount (SM3)
 FP3035, 4 Pin Flatpack (FP4)
 BX3035, Connectorized Housing (H1)

Features

- High Output Power: +28.5 dBm Typical
- Medium Gain: 16 dB Typical
- Operating Temp. - 55 °C to +100 °C
- Environmental Screening Available

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +100 °C
Frequency	80 - 120 MHz	80 - 120 MHz
Gain (dB)	16	15 Min.
Power @ 1 dB Comp. (dBm)	+28.5	+27 Min.
Reverse Isolation (dB)	-22.5	-21.5 Max.
VSWR In	<1.9:1	2.0:1 Max.
Out	<1.25:1	2.0:1 Max.
Noise Figure (dB)	<3.0	5.0 Max.
Power Vdc	+11	+11
mA	200	215 Max.

Note: Care should always be taken to effectively ground the case of each unit.

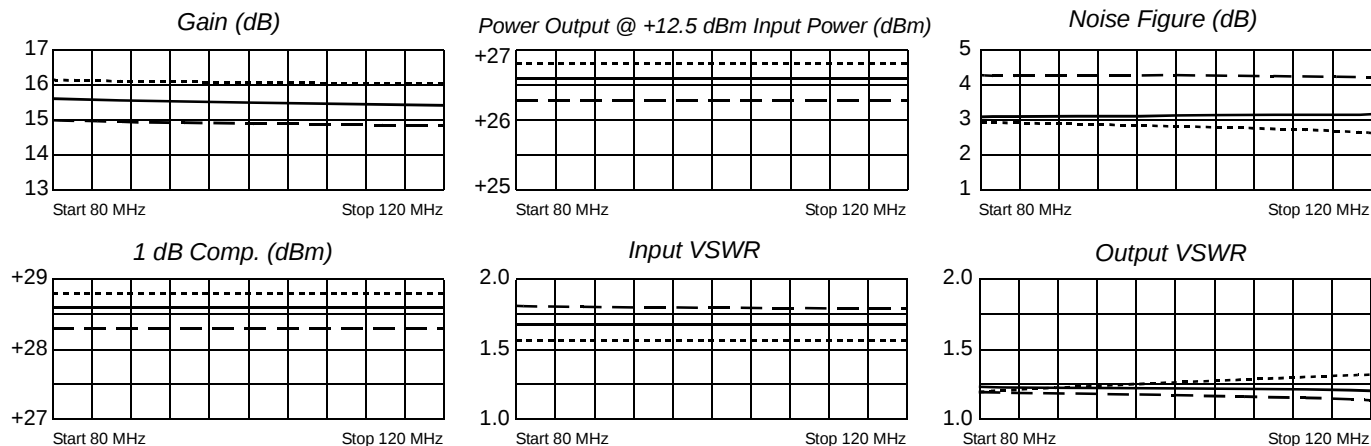
Typical Intermodulation Performance at 25 °C

Second Order Harmonic Intercept Point +56 dBm (Typ.)
 Second Order Two Tone Intercept Point +50 dBm (Typ.)
 Third Order Two Tone Intercept Point +45 dBm (Typ.)

Maximum Ratings

Ambient Operating Temperature -55°C to + 110 °C
 Storage Temperature -62°C to + 125 °C
 Case Temperature + 125 °C
 DC Voltage + 15 Volts
 Continuous RF Input Power + 20 dBm
 Short Term RF Input Power.... 200 Milliwatts (1 Minute Max.)
 Maximum Peak Power..... 0.5 Watt (3 µsec Max.)

Typical Performance Data



Legend ——— + 25 °C - - - - + 100 °C -55 °C

